SR120S --- SR1A0S

# SCHOTTKY BARRIER RECTIFIERS

### FEATURES

- $\diamondsuit$  Metal-Semiconductor junction with guard ring
- $\bigcirc$  Epitaxial construction
- $\diamondsuit$  Low forward voltage drop,low switching losses
- $\bigcirc$  High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- $\diamondsuit$  The plastic material carries U/L  $\,$  recognition 94V-0  $\,$

#### MECHANICAL DATA

- $\bigcirc$  Case:JEDEC A-405,molded plastic
- MIL- STD-202,Method 208
- $\diamond$  Polarity: Color band denotes cathode  $\diamond$  Weight: 0.008 ounces, 0.23 grams
- $\diamond$  Mounting position: Any

## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		SR120S	SR130S	SR140S	SR150S	SR160S	SR180S	SR1A0S	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	20	30	40	50	60	80	100	V
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	V
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	V
Maximum average forw ard rectified current 9.5mm lead length, (see fig.1)	I <sub>F(AV)</sub>	1.0							А
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load @T <sub>J</sub> =125℃	I <sub>FSM</sub>	40.0							A
Maximum instantaneous forw ard voltage @ 1.0A(Note 1)	V <sub>F</sub>	0.55			0.7		0.85		V
Maximum reverse current $@T_A=25^{\circ}C$ at rated DC blocking voltage $@T_A=100^{\circ}C$	I <sub>R</sub>	0.5 10.0							mA
Typical junction capacitance (Note2)	CJ	110							pF
Typical thermal resistance (Note3)	$R_{ extsf{ heta}JA}$	50							°C/W
Operating junction temperature range	Τ <sub>J</sub>	- :	- 55 + 125 - 55 + 150					°C	
Storage temperature range	T <sub>STG</sub>	- 55 +150							°C

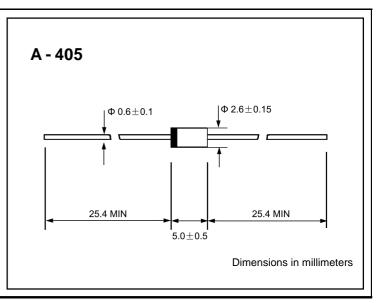
NOTE: 1. Pulse test :  $300 \ \mu$  s pulse width, 1% duty cycle.

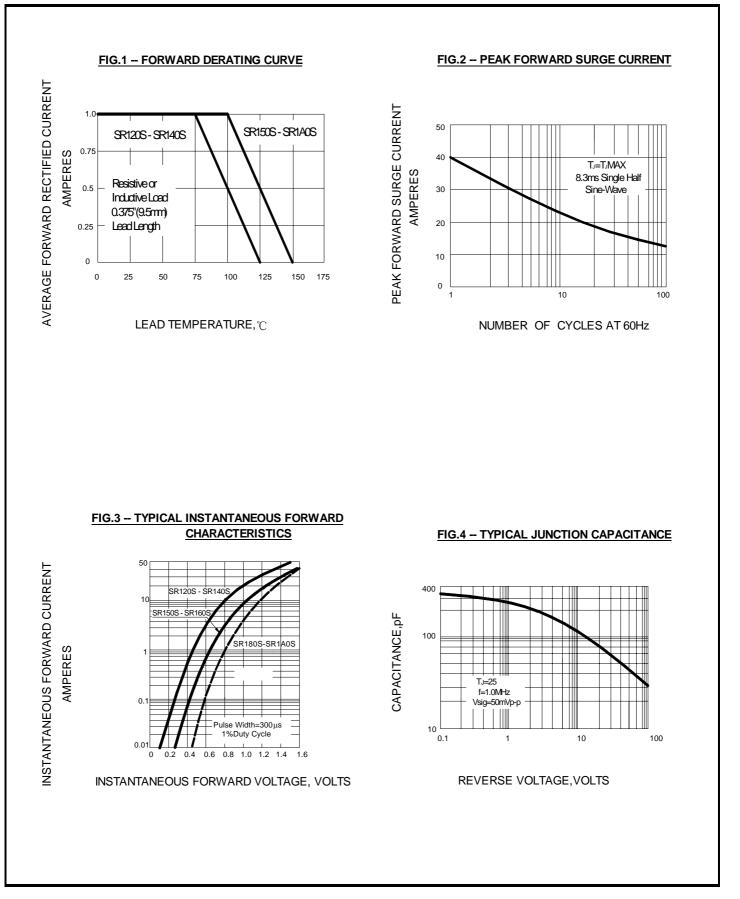
2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient

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## VOLTAGE RANGE: 20 --- 100 V CURRENT: 1.0A





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